

Unit IV : Data Converters and PLDs
(Weightage - 14 marks)

Practical Exam (SY - comp)

Questions

- * State two features of ADC 10809. (2m)
- * Specification of IC - DAC 0808. (2m)
- * Draw block diagram of Dual slope ADC and explain its working. (3m)
- * List types of DAC. (2m)
- * Describe working principle of successive approximation ADC. (3m)
- * Define Resolution & conversion time associated with ADC. (2m)

Compare

- * Compare between R-2R ladder DAC and weighted resistor DAC. (4m)
- * Compare following: i) RAM & ROM memory ii) EPROM & EEPROM. (2m)
- * Compare following: i) Volatile - Non-volatile memory ii) SRAM & DRAM. (4m)
- * Compare PLA & PAL. (4m)

Numericals

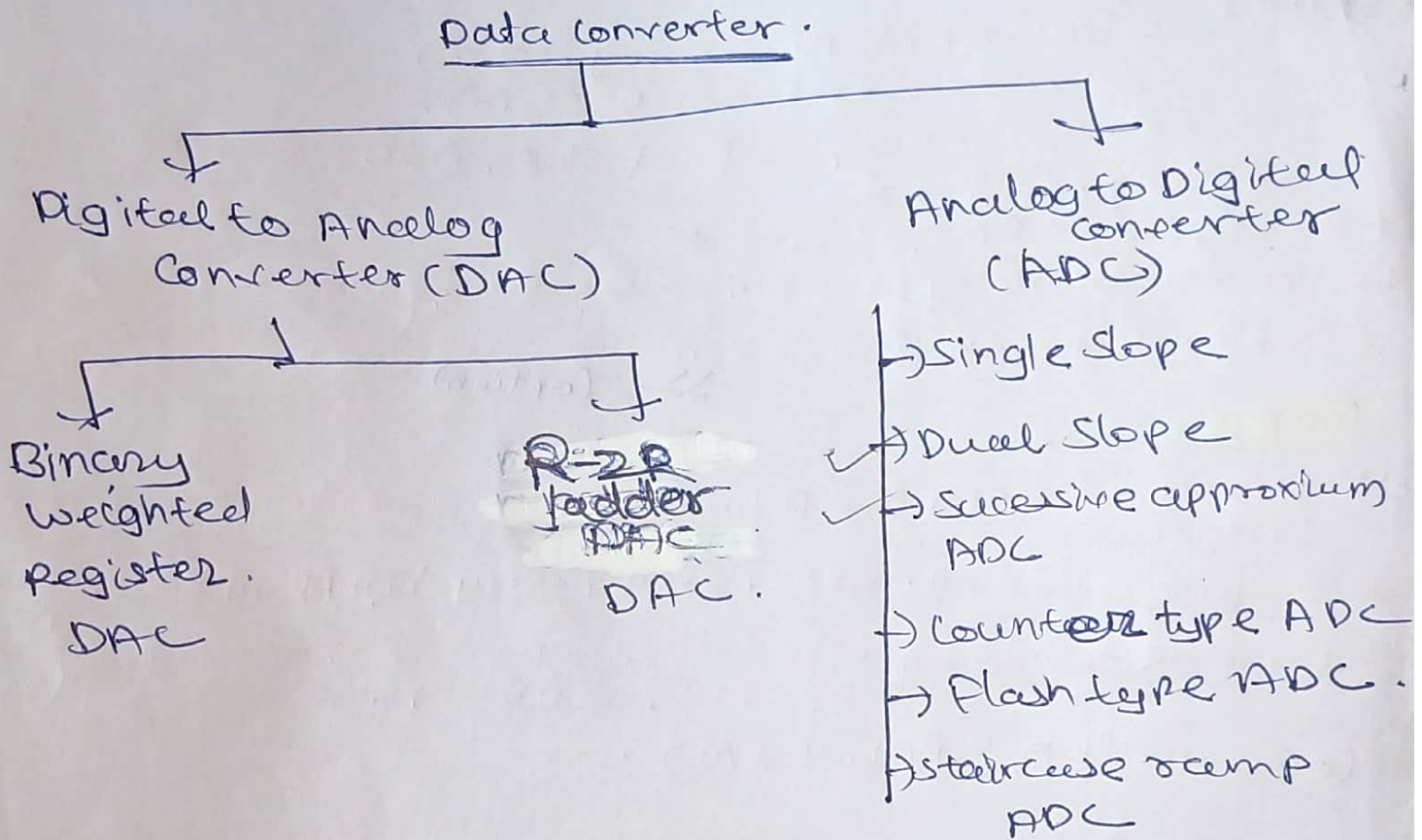
- Q/ Calculate the analog output of 4 bit DAC if the digital input is 1101. Assume $V_{FS} = 5V$. (4m)
- Q/ Calculate analog o/p of 4 bit DAC for digital input is 1100. Assume $V_{FS} = 5V$.
- Q/ Calculate the analog output for 4 bit weighted register type DAC for input -
i) 1011 ii) 1001 $V_{FS} = 5V$ (6m)

Fixed Question

- * Draw block diagram of Programmable Logic Array or Programmable Array Logic (4m)

Data Converter

A combinational Digital Circuit which converts the one form of data into other or vice versa, is called Data Converter.

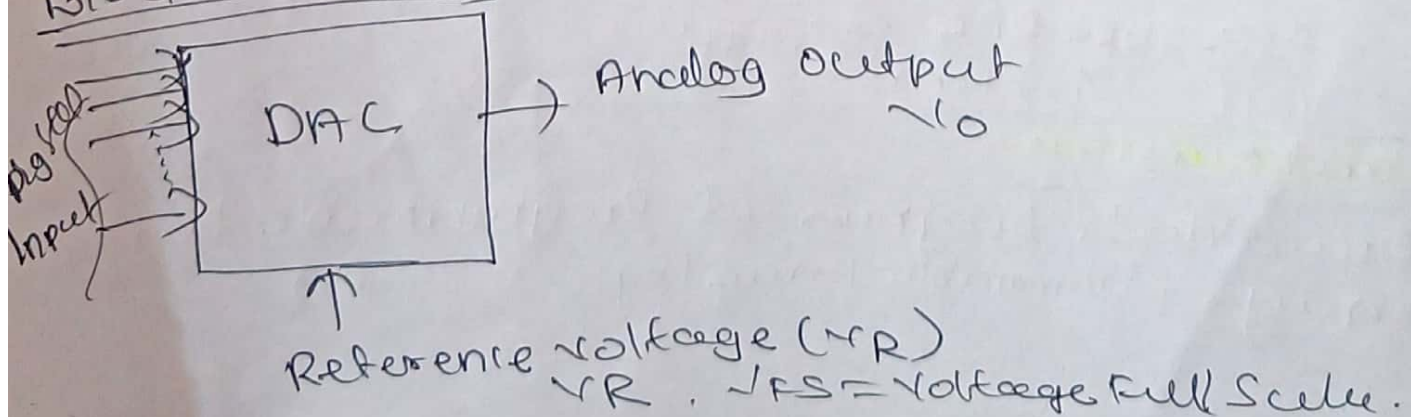


Digital to Analog Converter (DAC)

Q// List two types of DAC. (2m)

- ↳ Binary weighted Register DAC
- ↳ R-2R ladder DAC.

Block Diagram



Binary Weighted Register

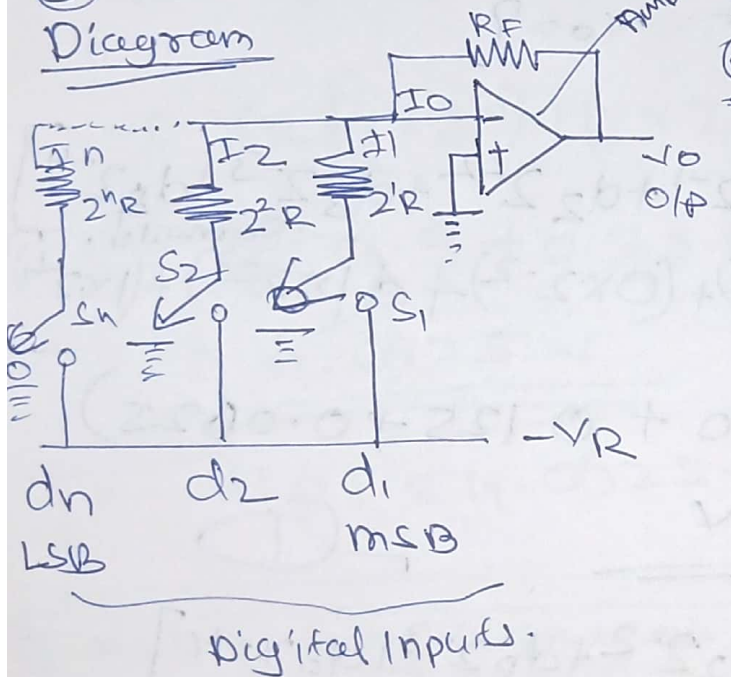
① It is simple in construction.

② It requires more than two resistor values.

③ It is not easy to extend for more number of bits.

④ It requires only one resistor per bit.

⑤ Diagram



⑦ Easy to implement.

⑧ Cheaper

⑨

$$V_R [d_1 2^{-1} + d_2 2^{-2} + \dots + d_n 2^{-n}]$$

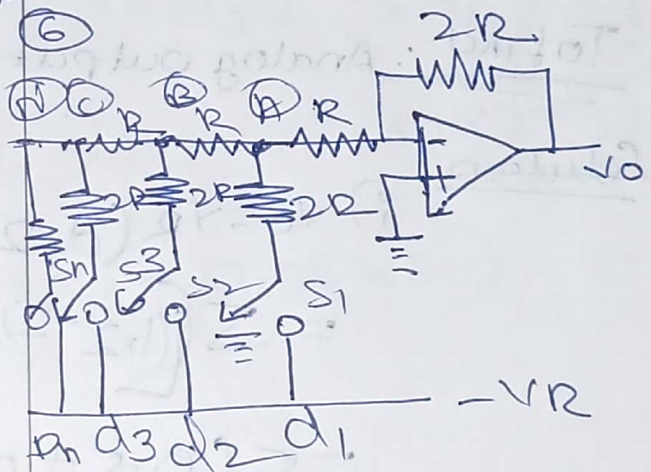
Binary (R-2R) Ladder Type

① It is slightly complicated in construction.

② It requires only two values of resistors.

③ It can be easily expanded to handle more number of bits by adding the resistor.

④ It requires two resistors per bit.



To overcome inaccurate value $2R$ came into existence Binary weighted Register.

⑦ Bit harder to implement.

⑧ Costly.

⑨

$$V_o = -\left(\frac{R_F}{R}\right) V_i = -\left(\frac{2R}{R}\right) \times \left(\frac{-V_R}{4}\right)$$

$$V_o = -V_R \frac{R_F}{R} \left(\frac{B_1}{2} + \frac{B_2}{2^2} + \dots + \frac{B_n}{2^n}\right)$$

Numericals

Q1 Calculate the analog output for 4 bit register type DAC for inputs $V_{FS} = 5V$.

i) 1011

ii) 1001

→ Given : 4 bit DAC.

$$V_{FS} = 5V = V_R$$

i) 1 0 1 1
d₁ d₂ d₃ d₄

ii) 1 0 0 1
d₁ d₂ d₃ d₄

To find : Analog output $V_o = ?$

Solution

$$\begin{aligned} \text{i) } V_o &= V_R (d_1 2^{-1} + d_2 2^{-2} + d_3 2^{-3} + d_4 2^{-4}) \\ &= 5 [(1 \times 2^{-1}) + (0 \times 2^{-2}) + (1 \times 2^{-3}) + (1 \times 2^{-4})] \\ &= 5 (0.5 + 0 + 0.125 + 0.0625) \\ &= \underline{3.4375V} \quad \text{①} \end{aligned}$$

$$\begin{aligned} \text{ii) } V_o &= V_R (d_1 2^{-1} + d_2 2^{-2} + d_3 2^{-3} + d_4 2^{-4}) \\ &= 5 [(1 \times 2^{-1}) + (0 \times 2^{-2}) + (0 \times 2^{-3}) + (1 \times 2^{-4})] \\ &= 5 (0.5 + 0 + 0 + 0.0625) \\ &= \underline{2.8125V} \quad \text{②} \end{aligned}$$

Ans ① & ②

1011	2	3.4375V
1001	2	2.8125V

Calculate Analog output of 4bit DAC. If the digital input is 1101. Assume $V_{FS} = 5V$ (10m)

Given

4 bit DAC.

$$V_{FS} = V_R = 1101$$

Input: 1101.

1 1 0 1
d₁ d₂ d₃ d₄

To find: No Analog output.

Soln

$$V_o = V_R (d_1 2^{-1} + d_2 2^{-2} + d_3 2^{-3} + d_4 2^{-4})$$

$$= V_R [(1 \times 2^{-1}) + (1 \times 2^{-2}) + (0 \times 2^{-3}) + (1 \times 2^{-4})]$$

$$= 5 (0.5 + 0.25 + 0 + 0.0625)$$

$$= 4.0625V$$

$$\therefore 1101 = 4.0625V$$

Q// Calculate analog output of 4bit DAC for digital input is 1100. Assume $V_{FS} = 5V$. (10m)

Given

4 bit DAC.

Input = 1100

1 1 0 0
d₁ d₂ d₃ d₄

$$V_{FS} = 5V = V_R$$

To find

Analog output = ?
 $V_o = ?$

Solution

$$\begin{aligned}V_0 &= 4R(d_1 \times 2^{-1} + d_2 \times 2^{-2} + d_3 \times 2^{-3} + d_4 \times 2^{-4}) \\&= 5((1 \times 2^{-1}) + (1 \times 2^{-2}) + (0 \times 2^{-3}) + (0 \times 2^{-4})) \\&= 5(0.5 + 0.25) \\&= 5(0.75)\end{aligned}$$

$$V_0 = 3.75 \text{ V}$$

$$\therefore 1100 = 3.75 \text{ V}$$

State two features of A/D IC 0809. (2m)

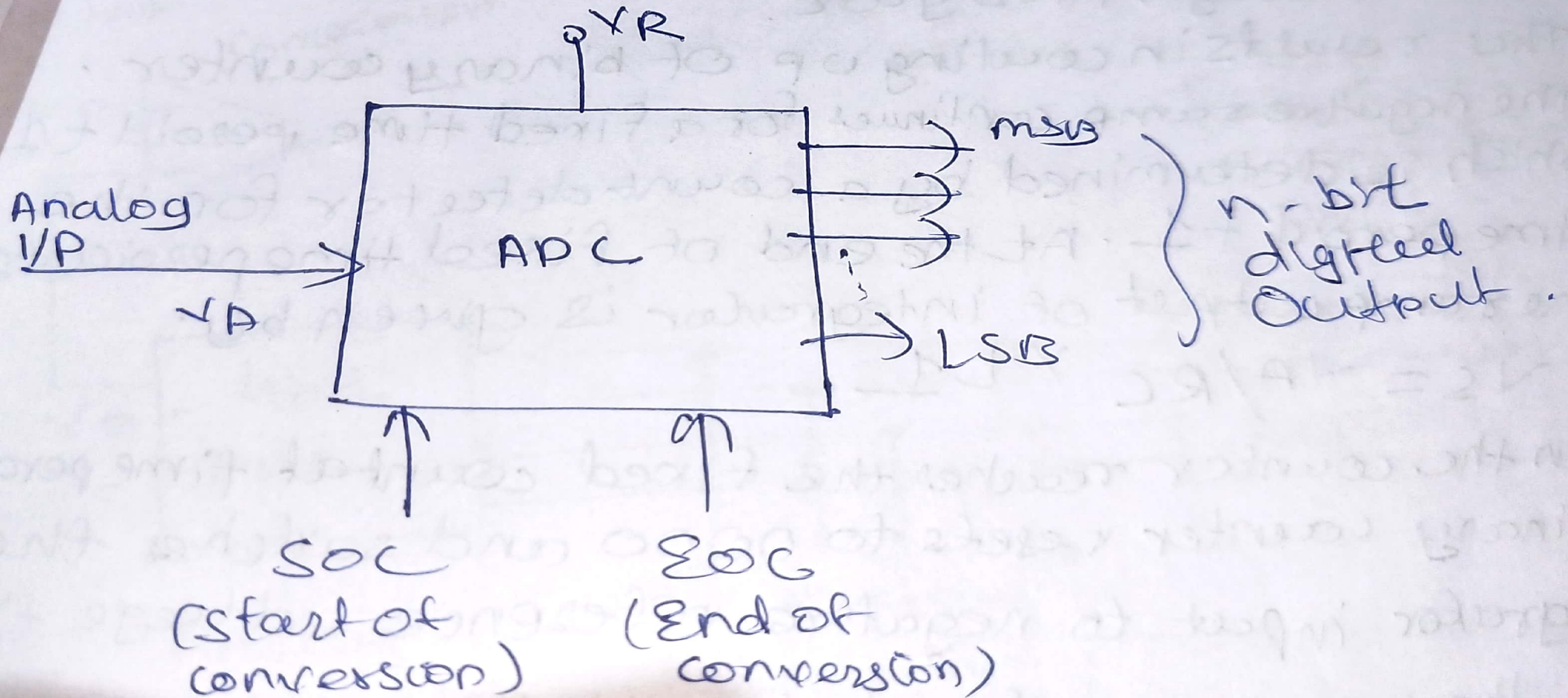
- ⇒ Easy interface to all microprocessors.
- * No zero or full-scale adjust required.
- * 8-channel multiplexer with address logic.
- * 0V to 5V input range with single 5V power supply.
- * Output meet TTL voltage level specification.
- * 0V to V_{CC} Input Range
- * 28-pin molded chip carrier package.

Specification of IC - DAC 0808 (2m).

- ⇒ The settling time is very fast 150 ns.
- * Higher power dissipation will be 1000 mW.
- * Resolution, Accuracy.
- * Linearity - Linearity is conventionally equal to deviation of performance of converter from a best straight line.
- * Format of Digital output - An A/D converter can be made for any standard digital code.
- * Analog input voltage: This is maximum allowable input voltage range.

log to digital

Block Diagram



Types of ADC

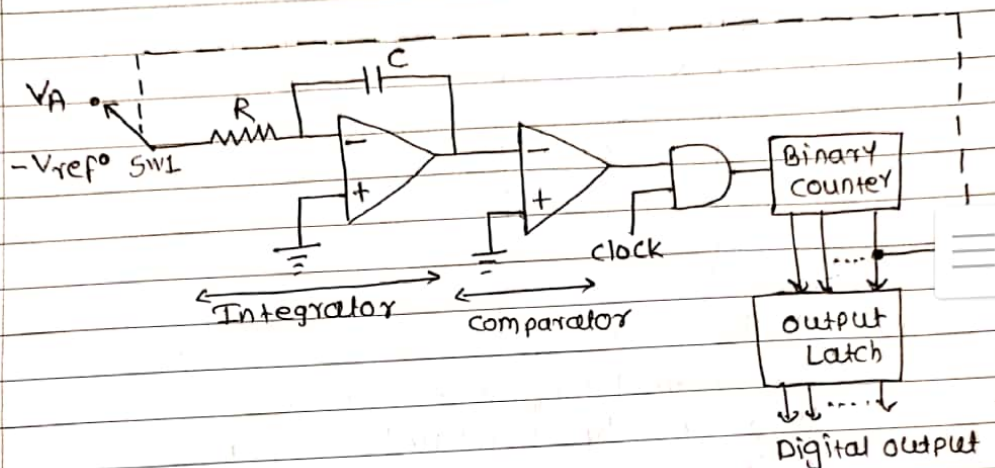
- 1) Successive Approximation TYPE ADC
- 2) Dual slope ADC.

1) Dual slope ADC

- In this, the integrator generates two different ramps, one with the known analog input voltage V_A and another with a known reference voltage $-V_{ref}$. Hence it is called as dual slope ADC.

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operation

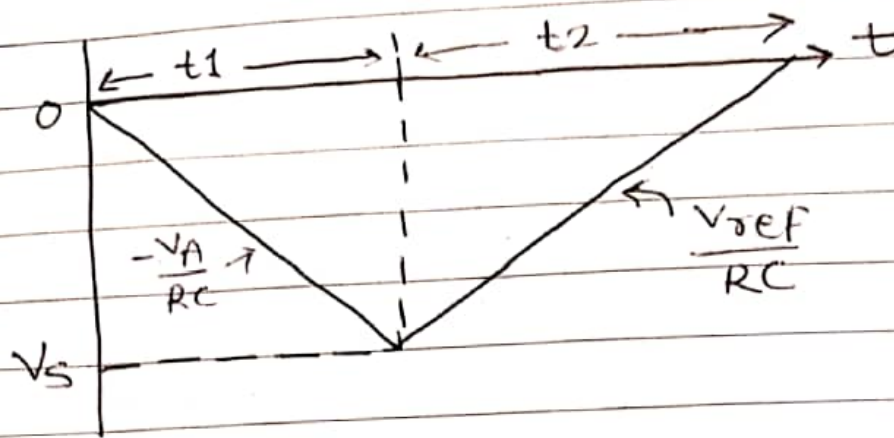
- First the analog input voltage V_A is connected to an integrator.
- The analog input voltage V_A is integrated by inverting integrator and generates a negative ramp output.
- The negative ramp continues for a fixed time period t_1 .

$$V_s = -\frac{V_A}{RC} \times t_1$$

- When the counter reaches the fixed count at time period t_1 , the binary counter resets to 0000 and switches the integrator input to a negative reference voltage $-V_{ref}$.

$$V_s = \frac{V_{ref}}{RC} \times t_2$$

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Since ramp generator voltage starts at 0V, decreasing down to $-V_s$ and then increasing up to 0V, the amplitude of negative and positive ramp voltages can be equated as

$$\frac{V_{ref}}{RC} \times t_2 = -\frac{V_A}{RC} \times t_1$$

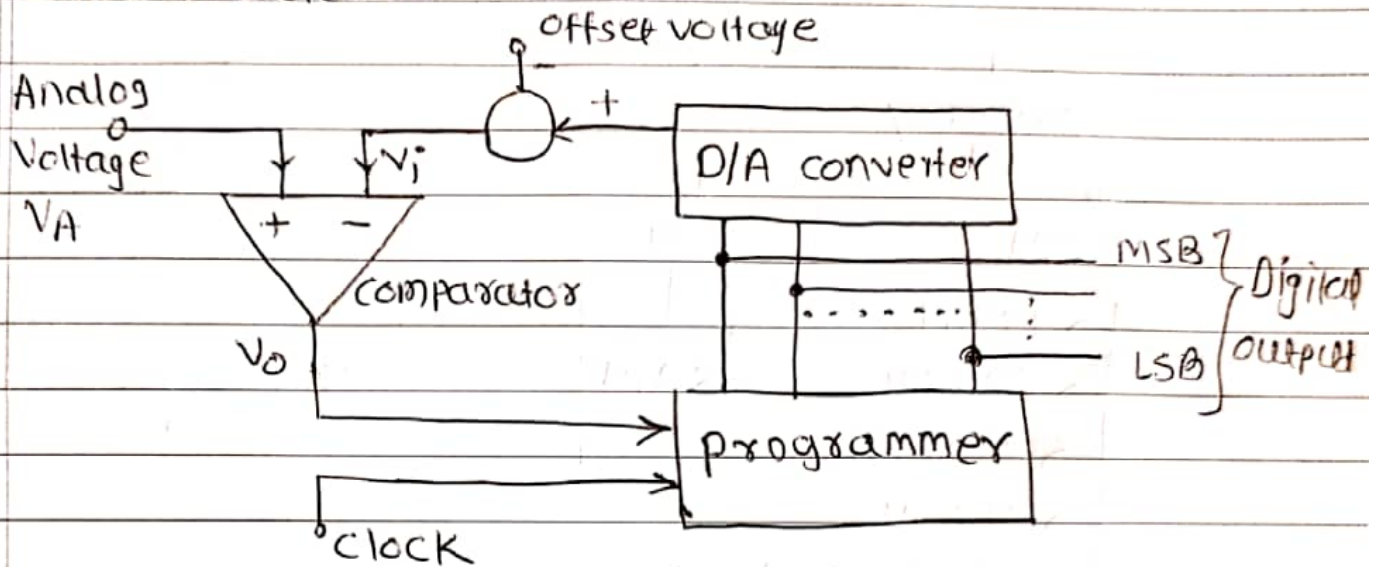
$$t_2 = -t_1 \frac{V_A}{V_{ref}}$$

$$V_A = -V_{ref} \times \frac{t_2}{t_1}$$

Thus the unknown analog input voltage V_A is proportional to the time period t_2 .

* Draw the circuit of successive approximation type ADC and explain its working.

→ The successive approximation A/D converter is shown below:



- An analog voltage (V_A) is constantly compared with voltage V_i , using a comparator.
- The output produced by comparator (V_o) is applied to an electronic programmer.
- If $V_A = V_i$ then $V_o = 0$ & then no conversion is required. The programmer displays the value of V_i in the form of digital o/p.
- But if $V_A > V_i$, then value of V_i is increased by 50% of earlier value.
- If $V_A < V_i$, then V_i is decreased by 50% of earlier value.
- This new value is converted into analog form by D/A converter so as to compare it with V_A again. This procedure is repeated till we get $V_A = V_i$.

* List various specifications of DAC.

→ 1) Resolution:

The smallest possible change in the analog output that is affected by a unit change (i.e. one bit) in digital input is known as the resolution of DAC.

$$\% \text{ Resolution} = \frac{V_{fs}}{2^n - 1} \times 100, \text{ where } V_{fs} \rightarrow \text{Full scale voltage}$$

2) Linearity:

The linearity of DAC is a measure of the precision with which the linear input output relationship is satisfied.

3) Accuracy:

The accuracy of DAC is defined as the closeness of the output analog voltage to the expected

4) Settling time:

It is defined as the amount of time necessary to settle to an analog output value of desired accuracy i.e. within $\frac{1}{2}$ LSB of the final value after the digital input has changed.

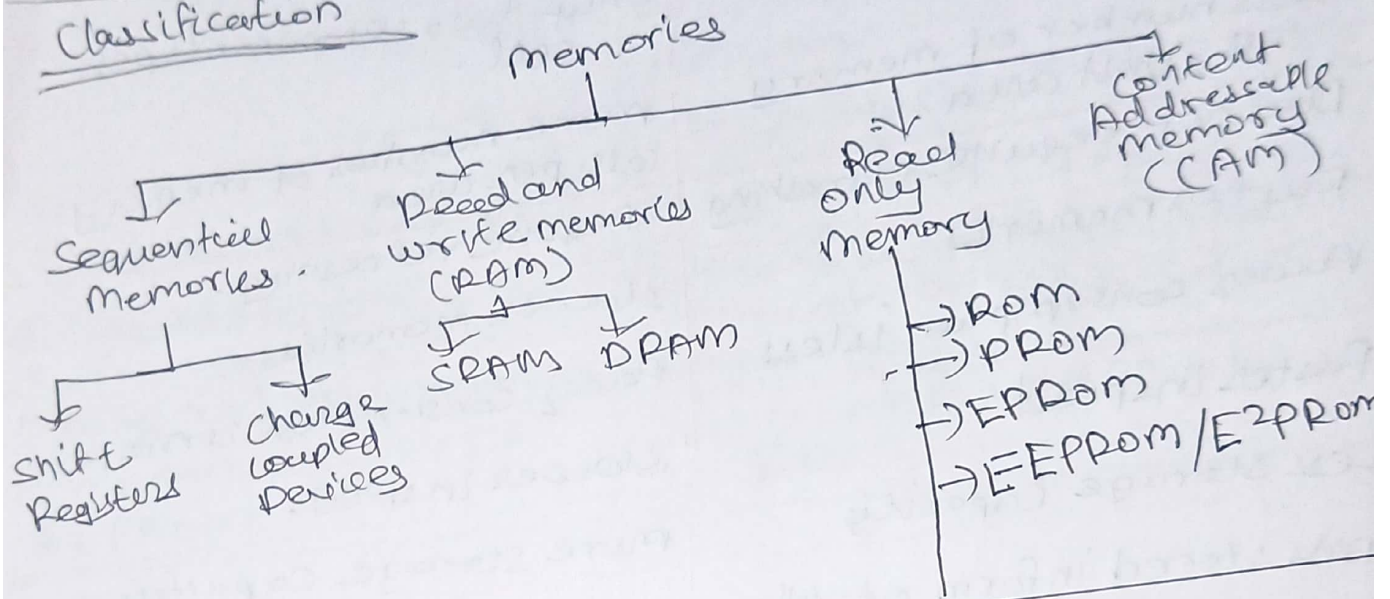
5) Temperature stability:

The analog output of DAC should not change due to change in temperature.

6) Speed: It is defined as the time needed to perform a conversion from digital to analog.

- Memories
- The subsystem of digital processing system which provides the storage facility is referred to as memory.
- Till recently, the memories used were mostly of magnetic type.
- But nowadays semiconductor have become popular due to their small size, low cost, high speed, high reliability and ease of expansion of memory size.

Classification



Compare RAM/ROM

RAM

- ① RAM stands for Random Access memory.
- ② Both Read and write operations can be performed.
- ③ These are volatile memory

④ Types: SRAM (Static RAM)
DRAM (Dynamic RAM)

⑤ Applications
Computer, calculator

⑥ Temporary Storage

⑦ writing data faster and stores in MB's

ROM

① ROM stands for Read Only memory

② Only Read operations can be performed

③ these are non-volatile memory.

④ Types: PROM, EPROM, E2/EEPROM

⑤ Applications
Computer, microprocessor

⑥ Permanent Storage

⑦ writing data slower and stores in GB's

Compare SRAM/DRAM
Compare SRAM/DRAM

SRAM

SRAM stands for Static Random Access memory.
Each static RAM cell is flip flop.

more number of components per cell.

Less number of memory cell / unit area

Does not require refreshing

Faster memories

Power consumption is less

Faster in speed.

Less storage capacity

Bits stored in form of voltage

Cheaper

Compare Volatile & Non-volatile memory

Volatile memory

The memory required electrical power supply to keep information stored is called volatile memory.

All RAMs are volatile memories

Information stored is lost when power is switched off.

Used for temporary storage of information.

Stored information is retained as long as power is on.

DRAM

DRAM stands for Dynamic Random Access Memory.
Each dynamic RAM cell consist of MOSFET and a capacitor

only two components per cell.

more number of memory cell per area

Require refreshing.

Slower memories.

Power consumption is more slower in speed.

more storage capacity.

Bits stored in form of charges

Expensive.

Non-volatile memory

Memory that will storing info. without need of electrical power is called non-volatile memory

All ROMs, ~~and~~ EPROMs are non-volatile memories. Information stored is retained even after power is off.

Used for permanent storage of information.

No effect of power, on stored information.

EEPROM and EEPROM / E²PRom

EEPROM

EEPROM stands for Electrically Erasable Programmable Read only memory.

Can be erased by using electrical signal.

Can be erased in small time 10ms.

Low density

Expensive than EPROM.

Not required to remove the chip from the circuit for erasing and reprogramming.

It modern version of EPROM.

EPROM

EPROM stands for Erasable Programmable Read only memory

Ultraviolet light is used to erase the content of EPROM

Requires 20-30min for erasing.

High density.

Cheaper than EEPROM.

Chip has to be removed from the circuit for erasing & reprogramming.

It is modern version of PRom.

(Optional)

Compare EPROM & Flash

EPROM

Can be erased only byte by byte by giving electric pulses.

Byte programmable

Cost is more

Programming is faster

Flash

Can be erased block by block by giving electric pulses.

Block programmable

Cost is less

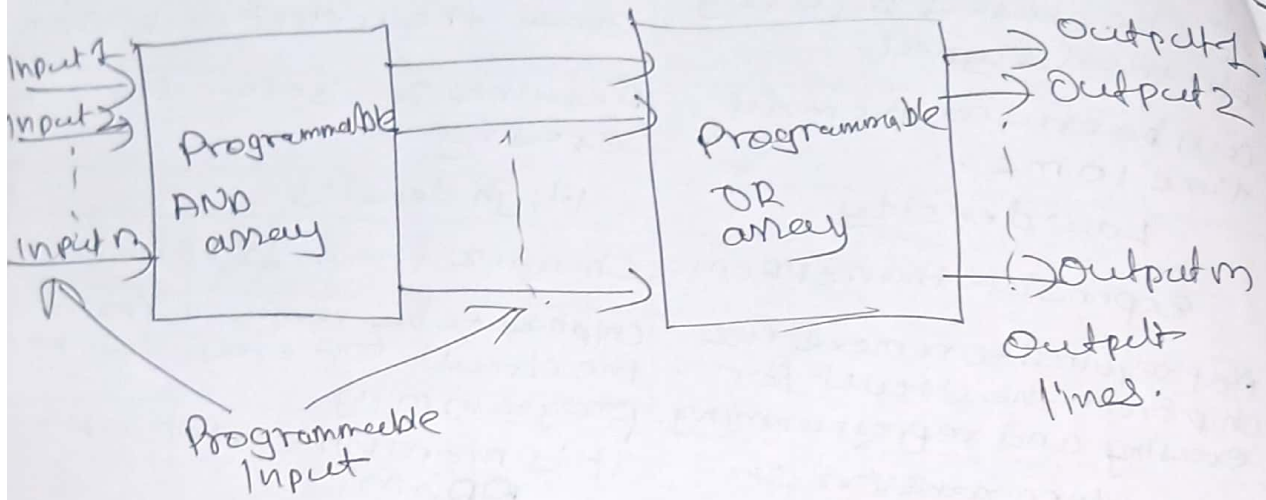
Programming is slower.

Programmable Logic Devices (PLDs)

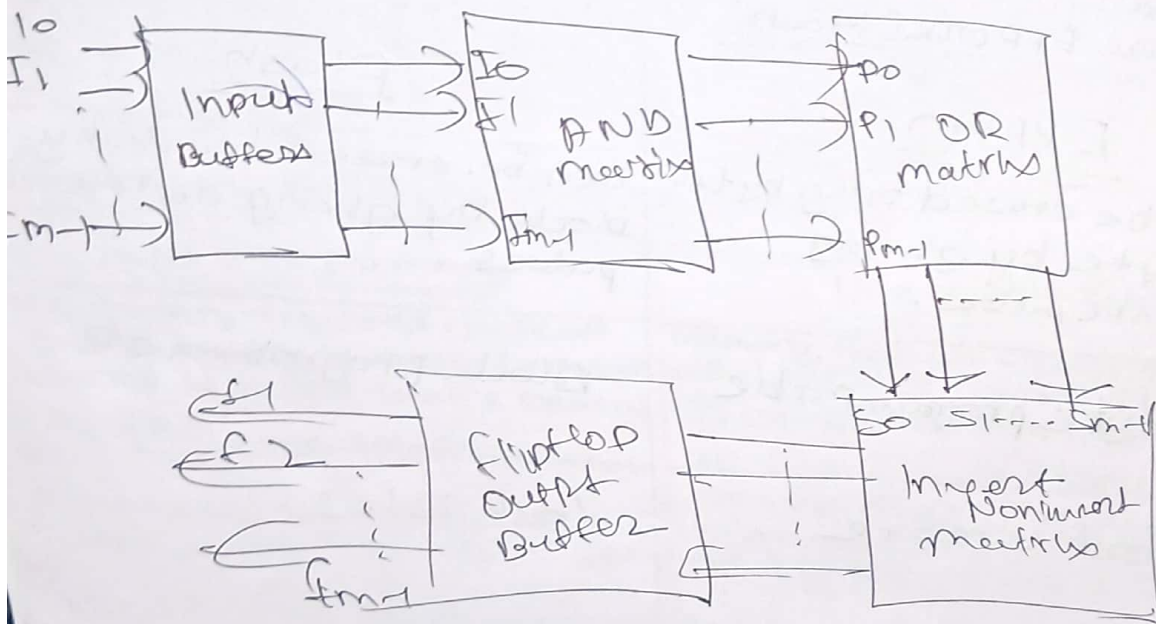
PLD
PLA
PAL

An programmable logic devices is an electronic component used in to build reconfigurable of digital circuits.

Block Diagram of Programmable Logic Array. (PLA)

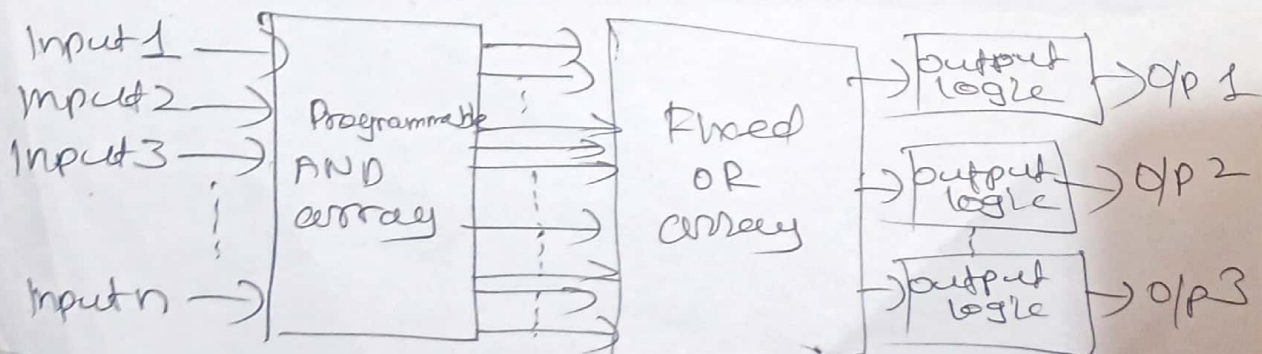


OR



Block Diagram of PAL

Programmable Array Logic



PLA

Programmable Logic Array

Both AND & OR array are Programmable.

It is costly

It is complex.

Large no. of function can be implemented.

Provides more programming flexibility.

It can implement SOP with any no. of terms.

PAL

Programmable Array Logic

OR array is fixed and AND array is programmable

It is cheaper

It is simple

Provides the limited no. of functions.

Offers less flexibility, but more likely to used.

It can implement SOP with limited no. of terms.